



# TCXO / VC-TCXO

## ULTRA HIGH STABILITY

# TG5032CCN

# TG5032SCN

- Frequency range : 10 MHz to 50 MHz
- Supply voltage : 3.3 V Typ. / 5.0 V Typ.
- Frequency / temperature characteristics :  $\pm 0.28 \times 10^{-6}$  Max. (for Stratum3)
- Frequency aging :  $\pm 3.0 \times 10^{-6}$  Max./20years(for Stratum3)
- External dimensions : 5.0  $\times$  3.2  $\times$  1.45 mm (4 pins)
- Applications : Network synchronization, Stratum3, Microwave BTS
- Features : Ultra high stability



Product Number (please contact us)  
**TG5032CCN : X1G005251xxxxxx**  
**TG5032SCN : X1G005261xxxxxx**



Actual size



## Specifications (characteristics)

Item	Symbol	TG5032CCN (CMOS)		TG5032SCN (Clipped sine wave)		Conditions / Remarks
		VC-TCXO	TCXO	VC-TCXO	TCXO	
Output frequency range	$f_o$	10 MHz to 50 MHz 10, 12.8, 15.36, 16.384, 19.44, 20, 24, 24.576, 25, 26, 27, 30.72, 40, 49.152, 50 MHz				Standard frequency
Supply voltage	$V_{CC}$	C: 3.3 V $\pm 5\%$ , H: 5.0 V $\pm 5\%$ (Supply voltage range :2.7 V to 5.5 V)				
Storage temperature	$T_{stg}$	-40 °C to +90 °C				Storage as single product
Operating temperature	$T_{use}$	G: -40 °C to +85 °C				
a) Frequency tolerance	$f_{tol}$	$\pm 1.0 \times 10^{-6}$ Max. (10 MHz $\leq f_o \leq 40$ MHz) $\pm 0.9 \times 10^{-6}$ Max. (40 MHz $< f_o \leq 50$ MHz)				After reflow, +25 °C
b) Frequency/temperature characteristics	$f_o-T_c$	B: $\pm 0.28 \times 10^{-6}$ Max. (for Stratum3) H: $\pm 0.25 \times 10^{-6}$ Max. (for Stratum3) : Option				-40 °C to +85 °C
c) Frequency/load coefficient	$f_o-Load$	$\pm 0.1 \times 10^{-6}$ Max. (10 MHz $\leq f_o \leq 40$ MHz) $\pm 0.2 \times 10^{-6}$ Max. (40 MHz $< f_o \leq 50$ MHz)				Load $\pm 10\%$
d) Frequency/voltage coefficient	$f_o-V_{CC}$	$\pm 0.1 \times 10^{-6}$ Max. (10 MHz $\leq f_o \leq 40$ MHz) $\pm 0.2 \times 10^{-6}$ Max. (40 MHz $< f_o \leq 50$ MHz)				$V_{CC} \pm 5\%$
e) Frequency aging	$f_{age}$	$\pm 0.5 \times 10^{-6}$ Max. $\pm 3.0 \times 10^{-6}$ Max. (for Stratum3)				+25 °C, First year +25 °C, 20 years
Holdover stability (Constant temperature)	-	$\pm 0.01 \times 10^{-6}$ Max. (+25 °C, 24 hours) $\pm 0.04 \times 10^{-6}$ Max. (+25 °C, 24 hours)				After 10 days of continuous operation. After 48 hours of continuous operation.
Free-run accuracy	-	$\pm 4.6 \times 10^{-6}$ Max.				This includes Item a),b),c),d) and e).
Current consumption	$I_{CC}$	5.0 mA Max. / 6.0 mA Max. 6.0 mA Max. / 8.0 mA Max. 8.0 mA Max. / 10.0 mA Max.		5.0 mA Max.		10 MHz $\leq f_o \leq 26$ MHz (3.3V / 5.0V) 26 MHz $< f_o \leq 40$ MHz (3.3V / 5.0V) 40 MHz $< f_o \leq 50$ MHz (3.3V / 5.0V)
Input resistance	$R_{in}$	100 k $\Omega$ Min.	—	100 k $\Omega$ Min.	—	Vc- GND (DC)
Frequency control range	$f_{cont}$	$\pm 5 \times 10^{-6}$ to $\pm 10 \times 10^{-6}$	—	$\pm 5 \times 10^{-6}$ to $\pm 10 \times 10^{-6}$	—	D : Vc=1.5 V $\pm$ 1.0 V at $V_{CC}$ =3.3 V E : Vc=1.65 V $\pm$ 1.0 V at $V_{CC}$ =3.3 V H : Vc=2.5 V $\pm$ 2.0 V at $V_{CC}$ =5.0 V
Frequency change polarity	—	Positive polarity	—	Positive polarity	—	
Symmetry	SYM	45 % to 55 %	—	—	—	GND level (DC cut)
Output voltage	$V_{OH}$	90 % $V_{CC}$ Min.	—	—	—	
	$V_{OL}$	10 % $V_{CC}$ Max.	—	—	—	
Output level	$V_{PP}$	—	—	0.8 V Min.	—	Peak to Peak
Rise time / Fall time	$t_r/t_f$	8.0 ns Max.	—	—	—	10% $V_{CC}$ to 90 % $V_{CC}$ level, Load:15 pF
Start-up time	$t_{str}$	5.0 ms Max.				T=0 at 90% $V_{CC}$
Output load condition	Load	15 pF	—	10 k $\Omega$ /10 pF	—	

\* Note : Please contact us for requirements not listed in this specification.

Product Name  
(Standard form)

**TG5032 C CN 30.720000MHz C B G N N A**

① ② ③ ④ ⑤ ⑥ ⑦ ⑧ ⑨

①Model ②Output (C: CMOS, S: Clipped sine wave) ③Frequency ④Supply voltage (C: 3.3 V Typ.)

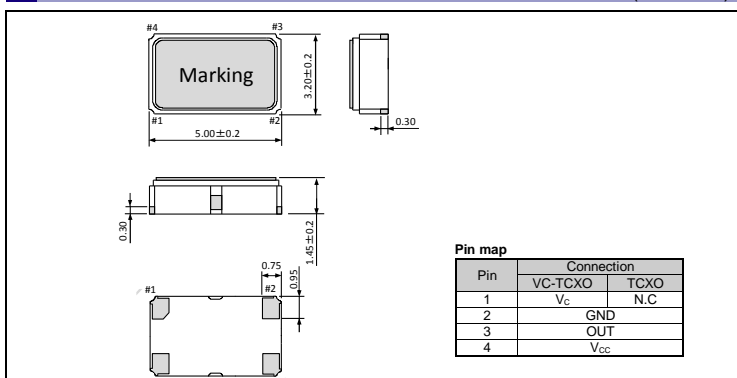
⑤Frequency/temperature characteristics (B:  $\pm 0.28 \times 10^{-6}$  Max.) ⑥Operating temperature (G: -40 °C to +85 °C)

⑦OE function (N: Non) ⑧Vc function (A: Vc =any, D: Vc =1.5 V, E: Vc =1.65 V, H: Vc =2.5 V, N: Non)

⑨Internal identification code ("A" is default)

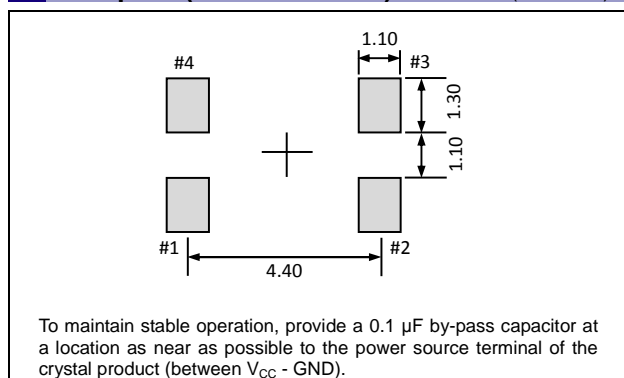
## External dimensions

(Unit :mm)



## Footprint (Recommended)

(Unit :mm)



## PROMOTION OF ENVIRONMENTAL MANAGEMENT SYSTEM CONFORMING TO INTERNATIONAL STANDARDS

At Seiko Epson, all environmental initiatives operate under the Plan-Do-Check-Action (PDCA) cycle designed to achieve continuous improvements. The environmental management system (EMS) operates under the ISO 14001 environmental management standard.

All of our major manufacturing and non-manufacturing sites, in Japan and overseas, completed the acquisition of ISO 14001 certification.

ISO 14000 is an international standard for environmental management that was established by the International Standards Organization in 1996 against the background of growing concern regarding global warming, destruction of the ozone layer, and global deforestation.





## WORKING FOR HIGH QUALITY

In order provide high quality and reliable products and services than meet customer needs,

Seiko Epson made early efforts towards obtaining ISO9000 series certification and has acquired ISO9001 for all business establishments in Japan and abroad. We have also acquired ISO/TS 16949 certification that is requested strongly by major automotive manufacturers as standard.

ISO/TS16949 is the international standard that added the sector-specific supplemental requirements for automotive industry based on ISO9001.

### ► Explanation of the mark that are using it for the catalog

	► Pb free.
	► Complies with EU RoHS directive. *About the products without the Pb-free mark. Contains Pb in products exempted by EU RoHS directive. (Contains Pb in sealing glass, high melting temperature type solder or other.)
	► Designed for automotive applications such as Car Multimedia, Body Electronics, Remote Keyless Entry etc.
	► Designed for automotive applications related to driving safety (Engine Control Unit, Air Bag, ESC etc ).

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